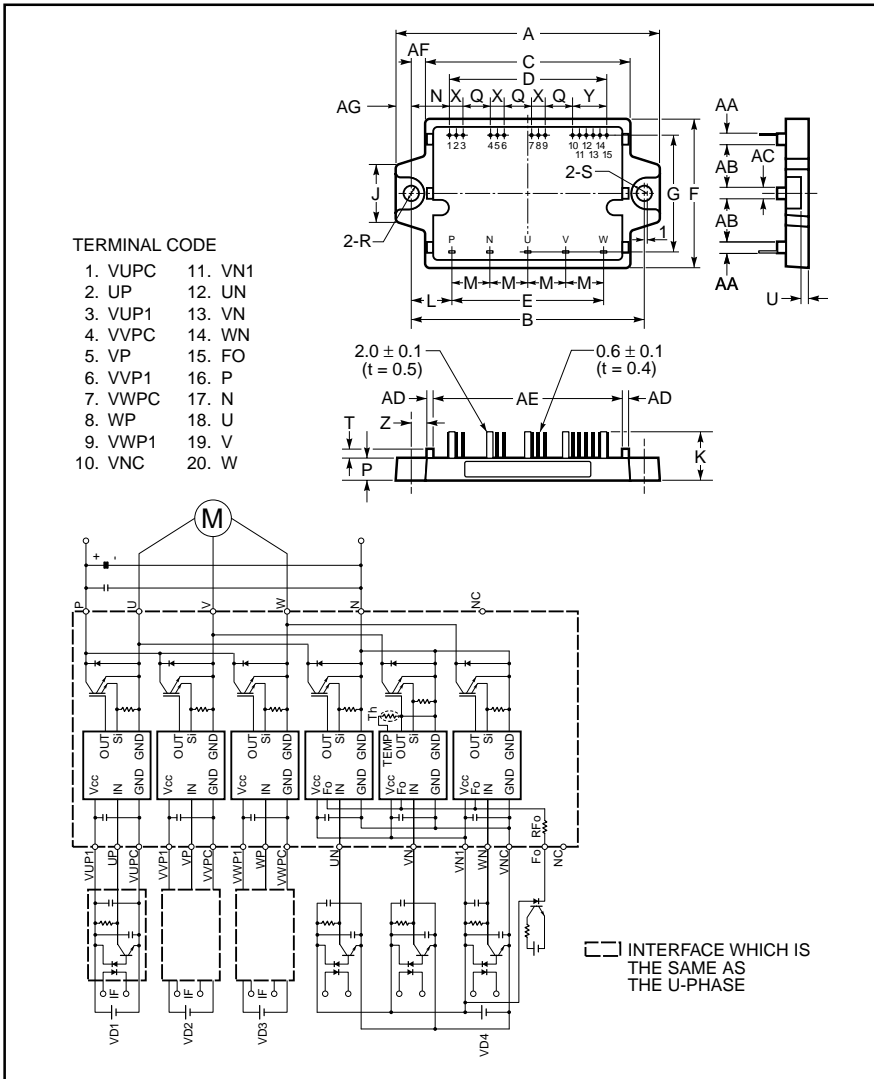


# PM10CZF120

FLAT-BASE TYPE  
INSULATED PACKAGE



**Description:**

Mitsubishi Intelligent Power Modules are isolated base modules designed for power switching applications operating at frequencies to 20kHz. Built-in control circuits provide optimum gate drive and protection for the IGBT and free wheel-diode power devices.

**Features:**

- Complete Output Power Circuit
- Gate Drive Circuit
- Protection Logic
  - Short Circuit
  - Over-Current
  - Over Temperature
  - Under Voltage

**Applications:**

- Inverters
- UPS
- Motion/Servo Control
- Power Supplies

**Ordering Information:**

Example: Select the Complete part number from the table below -i.e. PM10CZF120 is a 1200V, 10 Ampere Intelligent Power Module.

Type	Current Rating Amperes	V <sub>CEs</sub> Volts (x 10)
PM	10	120

**Outline Drawing and Circuit Diagram**

Dimensions	Inches	Millimeters
A	3.86±0.04	98.0±1.0
B	3.43±0.02	87.0±0.5
C	2.99	76.0
D	2.30	58.42
E	2.20±0.03	56.0±0.8
F	2.21±0.04	56.0±1.0
G	1.73±0.03	44.0±0.8
J	0.83	21.0
K	0.71±0.04	18.0±1.0
L	0.61	15.5
M	0.55±0.01	14.0±0.3
N	0.56	14.29
P	0.32±0.02	8.0±0.5
Q	0.40	10.16

Dimensions	Inches	Millimeters
R	0.22 Dia.	5.5 Dia.
S	0.24 Rad.	6.0 Rad.
T	0.14	3.5
U	0.12±0.02	3.0±0.5
X	0.1±0.01	2.54±0.3
Y	0.1±0.01	2.54±0.3
Z	0.24	6.0
AA	0.12	3.0
AB	0.69	17.5
AC	0.16	4.0
AD	0.10	2.5
AE	2.76	70.0
AF	0.22	5.5
AG	0.22	5.5

# PM10CZF120

FLAT-BASE TYPE  
INSULATED PACKAGE

## Absolute Maximum Ratings, $T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified

Ratings	Symbol	PM10CZF120	Units
Junction Temperature	$T_j$	-20 to 150	$^\circ\text{C}$
Storage Temperature	$T_{\text{stg}}$	-40 to 125	$^\circ\text{C}$
Case Operating Temperature	$T_C$	-20 to 100	$^\circ\text{C}$
Mounting Torque M5 Mounting Screws	–	1.47 ~ 1.96	N · m
Module Weight (Typical)	–	80	Grams
Supply Voltage Protected by OC and SC ( $V_D = 13.5 \sim 16.5\text{V}$ , Inverter Part)	$V_{\text{CC(prot)}}$	800	Volts
Isolation Voltage (Main Terminal to Baseplate, AC 1 min.)	$V_{\text{iso}}$	2500	Vrms

## Control Sector

Supply Voltage (Applied between $V_{\text{UP1}}-V_{\text{UPC}}$ , $V_{\text{VP1}}-V_{\text{VPC}}$ , $V_{\text{WP1}}-V_{\text{WPC}}$ , $V_{\text{N1}}-V_{\text{NC}}$ )	$V_D$	20	Volts
Input Voltage (Applied between $U_P-V_{\text{UPC}}$ , $V_P-V_{\text{VPC}}$ , $W_P-V_{\text{WPC}}$ , $U_N \cdot V_N \cdot W_N-V_{\text{NC}}$ )	$V_{\text{CIN}}$	20	Volts
Fault Output Supply Voltage (Applied between $F_O$ and $V_{\text{NC}}$ )	$V_{\text{FO}}$	20	Volts
Fault Output Current (Sink Current of $F_O$ Terminal)	$I_{\text{FO}}$	20	mA

## IGBT Inverter Sector

Collector-Emitter Voltage ( $V_D = 15\text{V}$ , $V_{\text{CIN}} = 15\text{V}$ )	$V_{\text{CES}}$	1200	Volts
Collector Current, ( $T_C = 25\text{ }^\circ\text{C}$ )	$I_C$	10	Amperes
Peak Collector Current, ( $T_C = 25\text{ }^\circ\text{C}$ )	$I_{\text{CP}}$	20	Amperes
Supply Voltage (Applied between P-N)	$V_{\text{CC}}$	900	Volts
Supply Voltage, Surge (Applied between P-N,)	$V_{\text{CC (surge)}}$	1000	Volts
Collector Dissipation	$P_C$	62	Watts

# PM10CZF120

FLAT-BASE TYPE  
INSULATED PACKAGE

## Electrical and Mechanical Characteristics, $T_j = 25\text{ }^\circ\text{C}$ unless otherwise specified

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
<b>Control Sector</b>						
Over Current Trip Level	OC	$-20^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$ , $V_D = 15\text{V}$	15	27	–	Amperes
Short Circuit Trip Level	SC	$-20^\circ\text{C} \leq T_j \leq 125^\circ\text{C}$ , $V_D = 15\text{V}$	–	41	–	Amperes
Over Current Delay Time	$t_{\text{off}}(\text{OC})$	$V_D = 15\text{V}$	–	10	–	$\mu\text{s}$
Over Temperature Protection	OT	Trip Level	100	110	120	$^\circ\text{C}$
	$\text{OT}_r$	Reset Level	–	90	–	$^\circ\text{C}$
Supply Circuit Under Voltage Protection	UV	Trip Level	11.5	12.0	12.5	Volts
	$\text{UV}_r$	Reset Level	–	12.5	–	Volts
Supply Voltage	$V_D$	Applied between $V_{\text{UP1}}-V_{\text{UPC}}$ , $V_{\text{VP1}}-V_{\text{VPC}}$ , $V_{\text{WP1}}-V_{\text{WPC}}$ , $V_{\text{N1}}-V_{\text{NC}}$	13.5	15.0	16.5	Volts
Circuit Current	$I_D$	$V_D = 15\text{V}$ , $V_{\text{CIN}} = 15\text{V}$ , $V_{\text{N1}}-V_{\text{NC}}$	–	18	25	mA
		$V_D = 15\text{V}$ , $V_{\text{CIN}} = 15\text{V}$ , $V_{\text{XP1}}-V_{\text{XPC}}$	–	7	10	mA
Input ON Threshold Voltage	$V_{\text{th(on)}}$	Applied between	1.2	1.5	1.8	Volts
Input OFF Threshold Voltage	$V_{\text{th(off)}}$	$U_P-V_{\text{UPC}}$ , $V_P-V_{\text{VPC}}$ , $W_P-V_{\text{WPC}}$ , $U_N \cdot V_N \cdot W_N-V_{\text{NC}}$	1.7	2.0	2.3	Volts
PWM Input Frequency	$f_{\text{PWM}}$	3- $\phi$ Sinusoidal	–	–	15	kHz
Fault Output Current	$I_{\text{FO(H)}}$	$V_D = 15\text{V}$ , $V_{\text{FO}} = 15\text{V}$	–	–	0.01	mA
	$I_{\text{FO(L)}}$	$V_D = 15\text{V}$ , $V_{\text{FO}} = 15\text{V}$	–	10	15	mA
Minimum Fault Output Pulse Width	$t_{\text{FO}}$	$V_D = 15\text{V}$	1.0	1.8	–	ms

**PM10CZF120**

 FLAT-BASE TYPE  
 INSULATED PACKAGE

**Electrical and Mechanical Characteristics,  $T_j = 25^\circ\text{C}$  unless otherwise specified**

Characteristics	Symbol	Test Conditions	Min.	Typ.	Max.	Units
<b>IGBT Inverter Sector</b>						
Collector-Emitter Cutoff Current	$I_{CES}$	$V_{CE} = V_{CES}, V_D = 15\text{V}, T_j = 25^\circ\text{C}$	–	–	1	mA
		$V_{CE} = V_{CES}, V_D = 15\text{V}, T_j = 125^\circ\text{C}$	–	–	10	mA
FwDi Forward Voltage	$V_{EC}$	$-I_C = 10\text{A}, V_D = 15\text{V}, V_{CIN} = 15\text{V}$	–	2.5	3.5	Volts
Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$V_D = 15\text{V}, V_{CIN} = 0\text{V}, I_C = 10\text{A}, T_j = 25^\circ\text{C}$	–	2.7	3.7	Volts
		$V_D = 15\text{V}, V_{CIN} = 0\text{V}, I_C = 10\text{A}, T_j = 125^\circ\text{C}$	–	2.5	3.4	Volts
Inductive Load Switching Times	$t_{on}$		0.3	0.6	1.3	$\mu\text{s}$
	$t_{rr}$	$V_D = 15\text{V}, V_{CIN} = 0 \leftrightarrow 15\text{V},$	–	0.15	–	$\mu\text{s}$
	$t_{C(on)}$	$V_{CC} = 600\text{V}, I_C = 10\text{A},$	–	0.3	1.0	$\mu\text{s}$
	$t_{off}$	$T_j = 125^\circ\text{C}, \text{ Inductive Load}$	–	1.8	3.3	$\mu\text{s}$
	$t_{C(off)}$		–	0.8	1.5	$\mu\text{s}$

**Thermal Characteristics**

Characteristic	Symbol	Condition	Min.	Typ.	Max.	Units
Junction to Case Thermal Resistance	$R_{th(j-c)Q}$	Each IGBT	–	–	2.0	$^\circ\text{C/Watt}$
	$R_{th(j-c)F}$	Each FwDi	–	–	5.5	$^\circ\text{C/Watt}$
Contact Thermal Resistance	$R_{th(c-f)}$	Case to Fin Per Module, Thermal Grease Applied	–	–	0.067	$^\circ\text{C/Watt}$

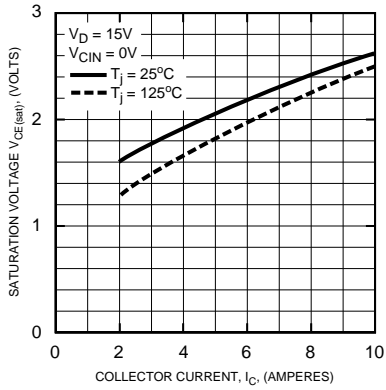
**Recommended Conditions for Use**

Characteristic	Symbol	Condition	Value	Units
Supply Voltage	$V_{CC}$	Applied across P-N Terminals	0 ~ 800	Volts
	$V_D$	Applied between $V_{UP1}-V_{UPC},$ $V_{N1}-V_{NC}, V_{VP1}-V_{VPC}, V_{WP1}-V_{WPC}$	$15 \pm 1.5$	Volts
Input ON Voltage	$V_{CIN(on)}$	Applied between	0 ~ 0.8	Volts
Input OFF Voltage	$V_{CIN(off)}$	$U_P, V_P, W_P, U_N, V_N, W_N$	$4.0 \sim V_D$	Volts
PWM Input Frequency	$f_{PWM}$	Using Application Circuit	5 ~ 15	kHz
Minimum Dead Time	$t_{dead}$	Input Signal	$\geq 3.0$	$\mu\text{s}$

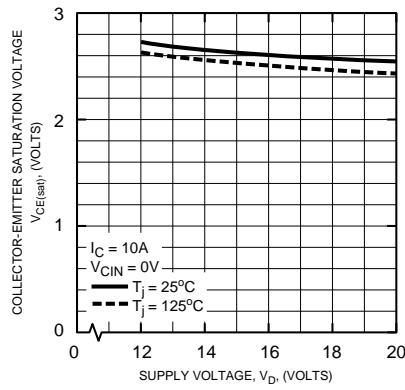
# PM10CZF120

FLAT-BASE TYPE  
INSULATED PACKAGE

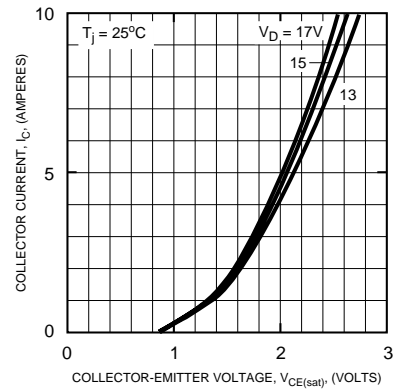
**SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)**



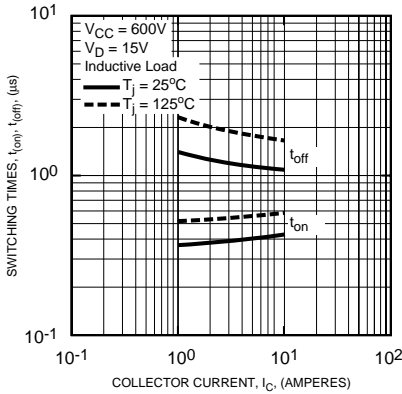
**COLLECTOR-EMITTER SATURATION VOLTAGE CHARACTERISTICS (TYPICAL)**



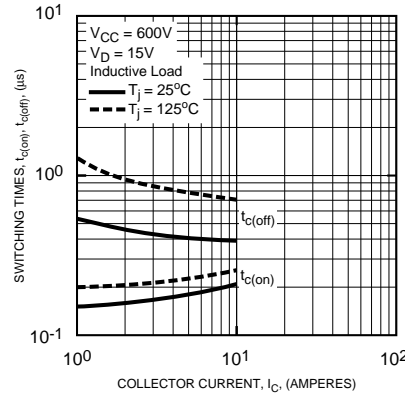
**OUTPUT CHARACTERISTICS (TYPICAL)**



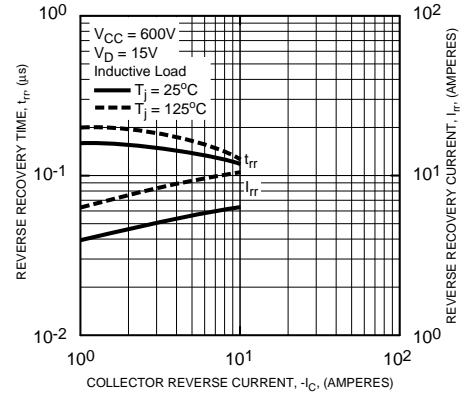
**SWITCHING TIME VS. COLLECTOR CURRENT (TYPICAL)**



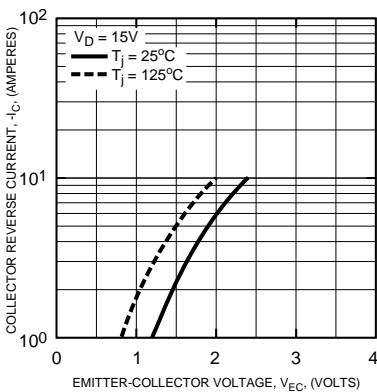
**SWITCHING TIME VS. COLLECTOR CURRENT (TYPICAL)**



**REVERSE RECOVERY CURRENT VS. COLLECTOR CURRENT (TYPICAL)**



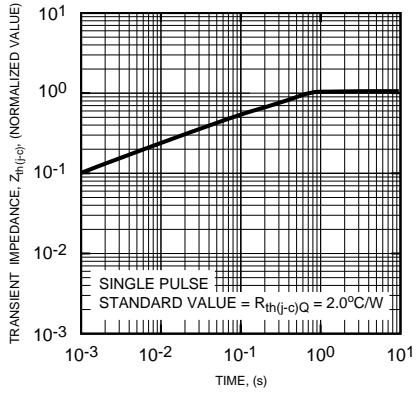
**FREE-WHEEL DIODE FORWARD CHARACTERISTICS (TYPICAL)**



**PM10CZF120**

FLAT-BASE TYPE  
INSULATED PACKAGE

TRANSIENT THERMAL  
IMPEDANCE CHARACTERISTICS  
(Each IGBT)



TRANSIENT THERMAL  
IMPEDANCE CHARACTERISTICS  
(Each FWDi)

